

# TRIAC(Through Hole/Isolated)

# TMG2C80F 5

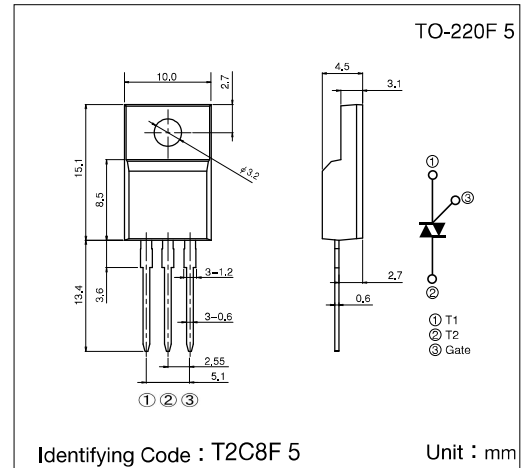
SanRex Triac TMG2C80F 5 is designed for full wave AC control applications. It can be used as an ON/OFF function or for phase control operation.

### Typical Applications

- Home Appliances : Washing Machines, Vacuum Cleaners, Rice Cookers, Micro Wave Ovens, Hair Dryers, other control applications
- Industrial Use : SMPS, Copier Machines, Motor Controls, Dimmer, SSR, Heater Controls, Vending Machines, other control applications

### Features

- $I_{T(RMS)}=2A$
- High Surge Current



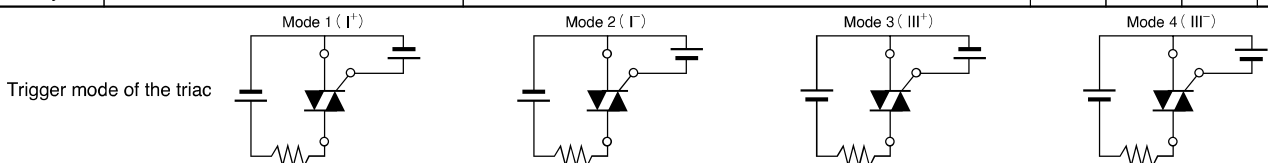
### Maximum Ratings

( $T_j=25^{\circ}C$  unless otherwise specified)

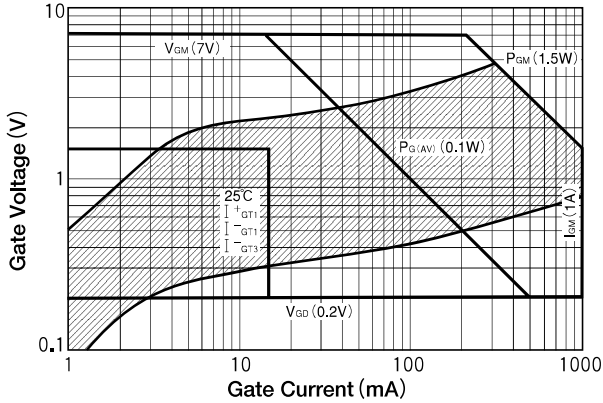
| Symbol       | Item                                | Reference  | Ratings         | Unit        |
|--------------|-------------------------------------|--|-----------------|-------------|
| $V_{DRM}$    | Repetitive Peak Off-State Voltage   |  | 800             | V           |
| $I_{T(RMS)}$ | R.M.S. On-State Current             | $T_c=105^{\circ}C$                               | 2               | A           |
| $I_{TSM}$    | Surge On-State Current              | One cycle, 50Hz/60Hz, Peak value, non-repetitive | 18/20           | A           |
| $I^2t$       | $I^2t$ (for fusing)                 |  | 1.67            | $A^2s$      |
| $P_{GM}$     | Peak Gate Power Dissipation         |  | 1.5             | W           |
| $P_{G(AV)}$  | Average Gate Power Dissipation      |  | 0.1             | W           |
| $I_{GM}$     | Peak Gate Current                   |  | 1               | A           |
| $V_{GM}$     | Peak Gate Voltage                   |  | 7               | V           |
| $V_{ISO}$    | Isolation Breakdown Voltage (R.M.S) | A.C.1minute                                      | 1500            | V           |
| $T_j$        | Operating Junction Temperature      |  | $-40 \sim +125$ | $^{\circ}C$ |
| $T_{stg}$    | Storage Temperature                 |  | $-40 \sim +150$ | $^{\circ}C$ |
|              | Mass                                |  | 2               | g           |

### Electrical Characteristics

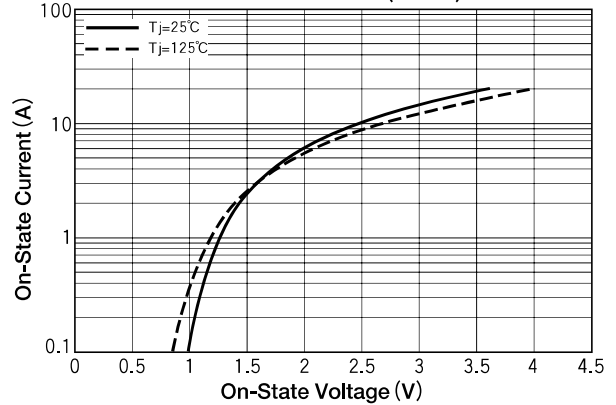
| Symbol        | Item  | Reference   | Ratings |      |      | Unit          |   |
|---------------|---|---|---------|------|------|---------------|---|
|               |   |   | Min.    | Typ. | Max. |               |   |
| $I_{DRM}$     | Repetitive Peak Off-State Current                         | $V_D=V_{DRM}$ , Single phase, half wave, $T_j=125^{\circ}C$ |         |      | 1    | mA            |   |
| $V_{TM}$      | Peak On-State Voltage                                     | $I_T=3A$ , Inst. measurement                                |         |      | 1.6  | V             |   |
| $I_{GT1}^+$   | Gate Trigger Current                                      | $V_D=6V$ , $R_L=10\Omega$                                   |         |      | 15   | mA            |   |
| $I_{GT1}^-$   |   |   |         |      | 15   |               |   |
| $I_{GT3}^+$   |   |   |         |      | —    |               |   |
| $I_{GT3}^-$   |   |   |         |      | 15   |               |   |
| $V_{GT1}^+$   | Gate Trigger Voltage                                      |   |         |      |      | 1.5           | V |
| $V_{GT1}^-$   |   |   |         |      |      | 1.5           |   |
| $V_{GT3}^+$   |   |   |         |      |      | —             |   |
| $V_{GT3}^-$   |   |   |         |      |      | 1.5           |   |
| $V_{GD}$      | Non-Trigger Gate Voltage                                  | $T_j=125^{\circ}C$ , $V_D=\frac{1}{2}V_{DRM}$               | 0.2     |      |      | V             |   |
| $(dv/dt)_c$   | Critical Rate of Rise of Off-State Voltage at Commutation | $T_j=125^{\circ}C$ , $(di/dt)_c=-1A/ms$ , $V_D=400V$        | 3       |      |      | $V/\mu s$     |   |
| $I_H$         | Holding Current   |   |         | 2    |      | mA            |   |
| $R_{th(j-c)}$ | Thermal Resistance  | Junction to case  |         |      | 7.5  | $^{\circ}C/W$ |   |
| $R_{th(j-a)}$ |   | Junction to ambient   |         |      | 50   | $^{\circ}C/W$ |   |



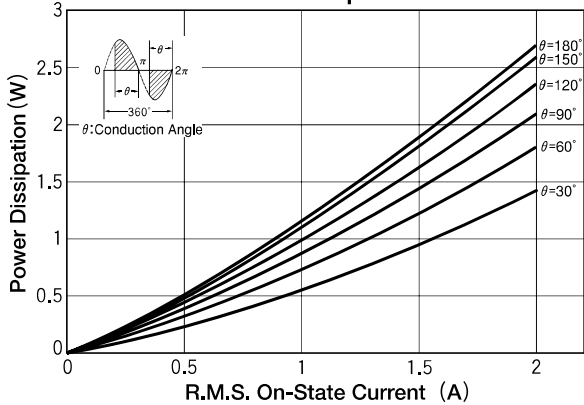
### Gate Characteristics



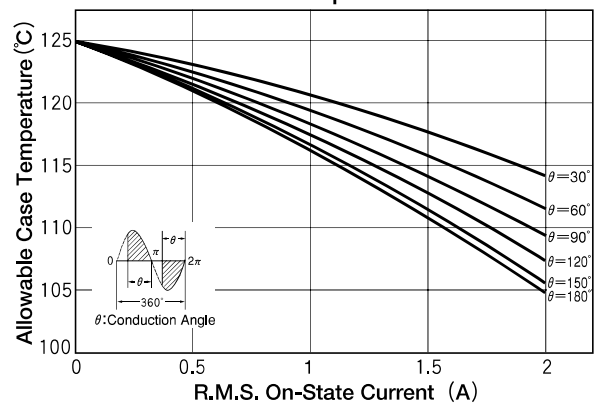
### On-State Characteristics (MAX)



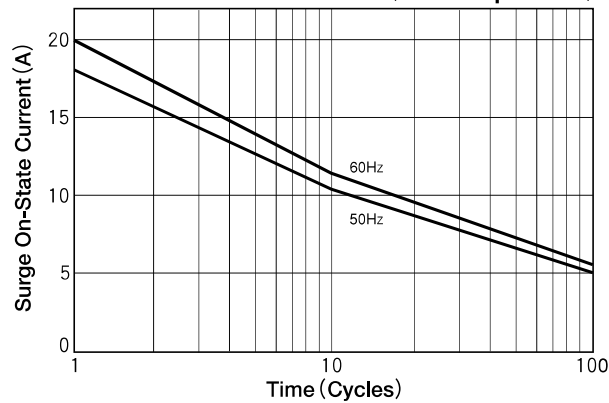
### R.M.S. On-State Current vs Maximum Power Dissipation



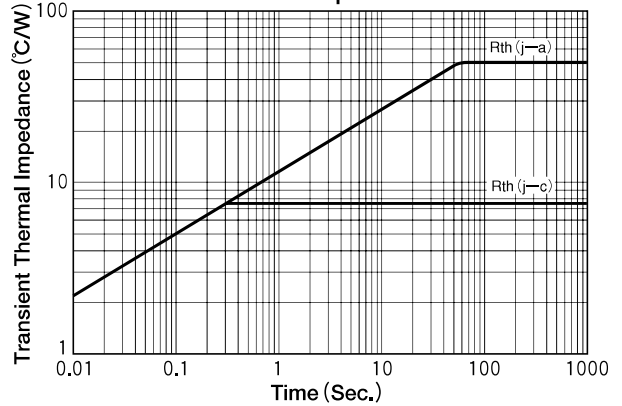
### R.M.S. On-State Current vs Allowable Case Temperature



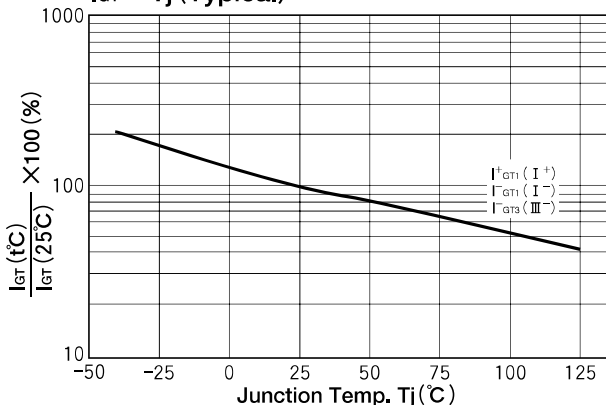
### Surge On-State Current Rating (Non-Repetitive)



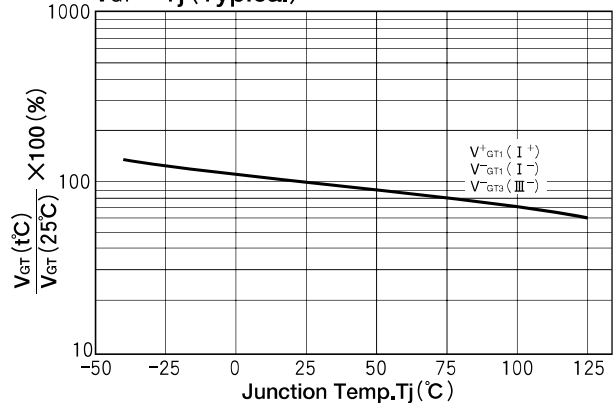
### Transient Thermal Impedance



### I<sub>GT</sub> - T<sub>j</sub> (Typical)



### V<sub>GT</sub> - T<sub>j</sub> (Typical)



R.M.S. On-State vs  
Allowable Ambient Temperature

